

**BC556/BC557/BC558**

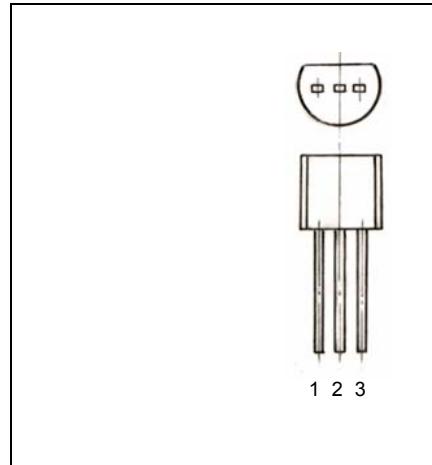
TRANSISTOR (PNP)

**FEATURES**

- High Voltage
- Complement to BC546/BC547/BC548

**MAXIMUM RATINGS (T<sub>A</sub>=25°C unless otherwise noted)**

Symbol	Parameter	Value	Units
<b>V<sub>CBO</sub></b>	Collector-Base Voltage BC556	-80	V
	BC557	-50	
	BC558	-30	
<b>V<sub>CEO</sub></b>	Collector-Emitter Voltage	-65	V
		-45	
		-30	
<b>V<sub>EBO</sub></b>	Emitter-Base Voltage	-5	V
<b>I<sub>C</sub></b>	Collector Current -Continuous	-100	mA
<b>P<sub>C</sub></b>	Collector Power Dissipation	625	mW
<b>T<sub>J</sub></b>	Junction Temperature	150	°C
<b>T<sub>stg</sub></b>	Storage Temperature	-55-150	°C

**ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
<b>Collector-base breakdown voltage</b> <b>BC556</b> <b>BC557</b> <b>BC558</b>	V <sub>CBO</sub>	I <sub>C</sub> = -100μA, I <sub>E</sub> =0	-80			V
			-50			
			-30			
<b>Collector-emitter breakdown voltage</b> <b>BC556</b> <b>BC557</b> <b>BC558</b>	V <sub>CEO</sub>	I <sub>C</sub> = -2mA , I <sub>B</sub> =0	-65			V
			-45			
			-30			
<b>Emitter-base breakdown voltage</b>	V <sub>EBO</sub>	I <sub>E</sub> = -100μA, I <sub>C</sub> =0	-5			V
<b>Collector cut-off current</b> <b>BC556</b> <b>BC557</b> <b>BC558</b>	I <sub>CBO</sub>	V <sub>CB</sub> = -70 V, I <sub>E</sub> =0 V <sub>CB</sub> = -45 V, I <sub>E</sub> =0 V <sub>CB</sub> = -25 V, I <sub>E</sub> =0			-0.1	μA
<b>Collector cut-off current</b> <b>BC556</b> <b>BC557</b> <b>BC558</b>	I <sub>CEO</sub>	V <sub>CE</sub> = -60 V, I <sub>B</sub> =0 V <sub>CE</sub> = -40 V, I <sub>B</sub> =0 V <sub>CE</sub> = -25 V, I <sub>B</sub> =0			-0.1	μA
<b>Emitter cut-off current</b> <b>BC556</b> <b>BC557</b> <b>BC558</b>	I <sub>EBO</sub>	V <sub>EB</sub> = -5 V, I <sub>C</sub> =0			-0.1	μA
<b>DC current gain</b> <b>BC556</b> <b>BC557</b> <b>BC558</b> <b>BC557A</b> <b>BC556B/BC557B/BC558B</b> <b>BC557C</b>	h <sub>FE</sub>	V <sub>CE</sub> =-5V, I <sub>C</sub> = -2mA	120		800	
			120		800	
			120		800	
			120		220	
			180		460	
			420		800	
<b>Collector-emitter saturation voltage</b>	V <sub>CE(sat)</sub>	I <sub>C</sub> =-100mA, I <sub>B</sub> = -5mA			-0.65	V
<b>Base-emitter saturation voltage</b>	V <sub>BE(sat)</sub>	I <sub>C</sub> = -100mA, I <sub>B</sub> =-5mA			-1	V
<b>Transition frequency</b>	f <sub>T</sub>	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA f = 100MHz	150			MHz